#### TOSHIBA TRANSISTOR SILICON N CHANNEL JUNCTION TYPE FET SILICON NPN EPITAXIAL TYPE TRANSISTOR

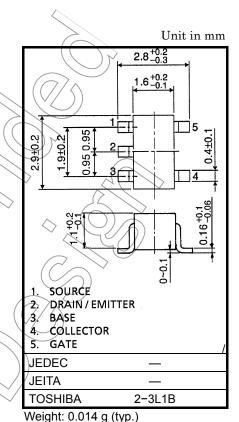
# HN3G01J

High Frequency Amplifier Applications AM High Frequency Amplifier Applications Audio Frequency Amplifier Applications

#### Absolute Maximum Ratings (Ta = 25°C)

Q1: FET

CHARACTERISTIC	SYMBOL	RATING	UNIT
Gate-Drain Voltage	V <sub>GDS</sub>	-20	V
Gate Current	l <sub>G</sub>	10	(A <
Q2: TRANSISTOR			
CHARACTERISTIC	SYMBOL	RATING	
Collector-Base Voltage	V <sub>CBO</sub>	60	V
Collector-Emitter Voltage	VCEO	50	X
Emitter-Base Voltage	CEBO	5	/ (v



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

lc

 $I_B$ 

temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

mÀ

mΑ

150

30

#### **Common Ratings**

Collector Current

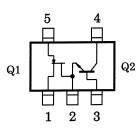
**Base Current** 

CHARACTERISTIC	SYMBOL	RATING	UNIT
Power Dissipation	P*	200	mW
Junction Temperature	( T <sub>j</sub> )	125	°C
Storage Temperature Range	Tstg	-55~125	°C

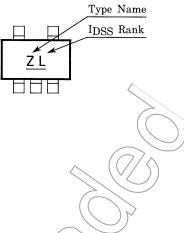
\*: Total Rating

## TOSHIBA

### Pin Assignment (Top View)



#### Marking



### Electrical Characteristics (Ta = 25°C)

				$\frown$		
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = -15V, V <sub>DS</sub> = 0		$\sum$	> -1.0	nA
Gate-Drain Breakdown Voltage	V <sub>(BR)</sub> GDS	V <sub>DS</sub> = 0, I <sub>G</sub> = -100µA	-20	1 A	) —	V
Drain Current	I <sub>DSS</sub> (Note)	$V_{DS} = 5V, V_{GS} = 0$	6	Z	32	mA
Gate-Source Cut-off Voltage	V <sub>GS</sub> (OFF)	V <sub>DS</sub> = 5V, D = 1µA		< 	-2.5	V
Forward Transfer Admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 5V, V <sub>GS</sub> = 0, f = 1kHz	-15	25	_	mS
Input Capacitance	C <sub>iss</sub>	$V_{DS} = 5V, V_{GS} = 0, f = 1MHz$	<u> </u>	7.5	10	pF
Reverse Transfer Capacitance	C <sub>rss</sub>	$V_{DG} = 5V$ , $I_D = 0$ , $f = 1MHz$	/ _	2	3	pF

Note: I<sub>DSS</sub> Classification

GR: 6~12mA, BL: 10~20mA, V: 16~32mA (G) (L) (V)

 $(\ )\ldots$  I\_{DSS} Rank Marking

Q2

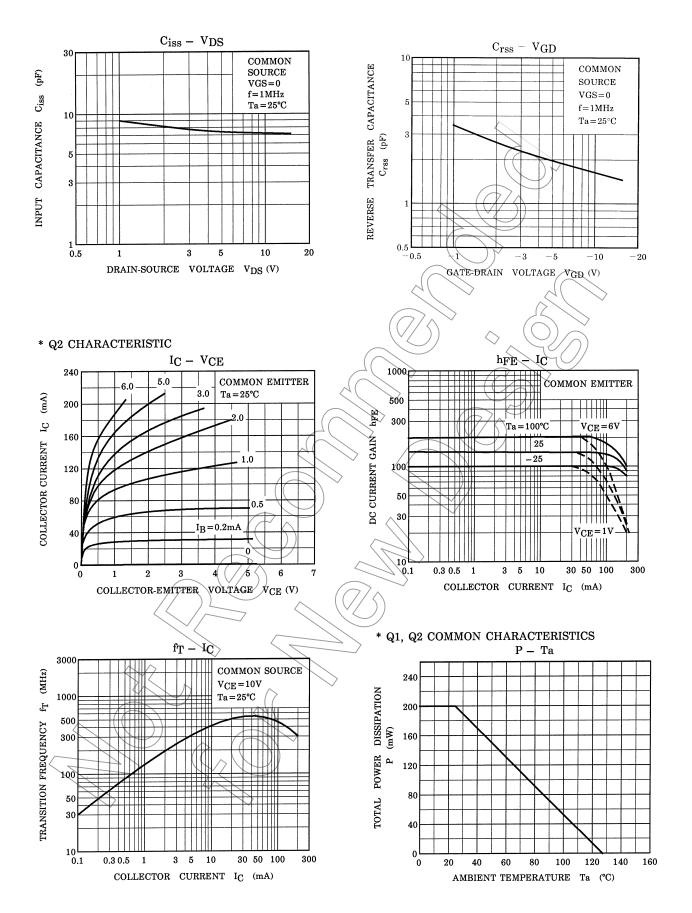
QZ	$\sum_{n}$					
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	Ісво	$V_{CB} = 60V / I_{E} = 0$	—	_	0.1	μA
Emitter Cut-off Current	/TEBO	V <sub>EB</sub> = 5V, I <sub>C</sub> = 0	—	-	0.1	μA
DC Current Gain	hfe	$V_{CE} = 6V, I_C = 2mA$	120	_	400	
Collector-Emitter Saturation Voltage	VCE (sat)	H <sub>C</sub> = 100mA, I <sub>B</sub> = 10mA	_	0.1	0.25	V
Transition Frequency	< √ (f <sub>T</sub>	V <sub>CE</sub> = 10V, I <sub>C</sub> = 1mA	60	_	_	MHz
Collector Output Capacitance	Cob	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1MHz	—	2.0	3.5	pF

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\* Q1 CHARACTERISTICS

#### ID - VDS (LOW VOLTAGE REGION) $I_D - V_{DS}$ 20 20 COMMON SOURCE Ta=25°C COMMON SOURCE $V_{GS} = 0V$ $Ta = 25^{\circ}C$ $V_{GS} = 0V$ (WW) (WA) 16 16 0.1 DRAIN CURRENT ID DRAIN CURRENT ID 0.1 1212 -0.2 -0.2 0.3 8 -0.3 -0.4 0.4 -0.5 -0.6 -0.7 -0.8 -0.5-0.6-0.70 01 12 16 20 24 12 16 20 24 0 8 4 8 Λ DRAIN-SOURCE VOLTAGE VDS (V) DRAIN-SOURCE VOLTAGE $V_{DS}(V)$ ID - VGS $|Y_{fs}|$ -(ID\$S 24 50 COMMON SOURCE ADMITTANCE IDSS=30mA $V_{DS} = 5V$ 20 (WW) 40 $Ta = 25^{\circ}C$ ď 16 30 CURRENT FORWARD TRANSFER 6 2 I<sub>DSS</sub>=23mA 20 COMMON DRAIN SOURCE $V_{DS} = 5V$ 10 f = 1 kHz $Ta = 25^{\circ}C$ Ó 0 -1.0 -0.8 -0.6 -0.4 -0.2 0 -1.2 -1.4 16 24 32 40 48 Q 8 GATE1-SOURCE VOLTAGE VGS (V) DRAIN CURRENT ID (mA) |Yfs| – IDSS VGS (OFF) - I<sub>DSS</sub> 300 TRANSFER ADMITTANCE [Yfs] (mS) COMMON SOURCE GATE-SOURCE CUT-OFF VOLTAGE COMMON SOURCE IDSS: $V_{DS} = 5V$ $v_{DS} = 5V$ $^{-3}$ $V_{GS}=0$ IDSS : VGS=0 |Yfs| : $V_{DS} = 5V$ $V_{DS} = 5V$ 100 VGS(OFF) $V_{GS}=0$ $I_D = 1 \mu A$ f = 1 kHz $Ta = 25^{\circ}C$ $Ta = 25^{\circ}C$ 50 FORWARD 30 -0.5 $\mathbf{5}$ 10 30 503 5 30 50 3 10 DRAIN CURRENT IDSS (mA) DRAIN CURRENT IDSS (mA)

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